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Vertical-Cavity Surface-Emitting Lasers XII

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Contents

vii	<i>Conference Committee</i>
ix	<i>Introduction</i>

SESSION 1 COMMERCIAL VCSELS

- 6908 02 **LW VCSELS for SFP+ applications (Invited Paper)** [6908-01]
L. A. Graham, J. L. Jewell, K. D. Maranowski, M. V. Crom, S. A. Feld, J. M. Smith, J. G. Beltran, T. R. Fanning, M. Schnoes, M. H. Gray, D. Droege, V. Koleva, M. Dudek, J. Fiers, JDSU (USA); R. Patterson, Maxim Integrated Products (USA)
- 6908 03 **Volume production of polarization controlled single-mode VCSELS** [6908-02]
M. Grabherr, R. King, R. Jäger, D. Wiedenmann, P. Gerlach, D. Duceck, C. Wimmer, ULM Photonics GmbH (Germany)
- 6908 05 **Developments at Finisar AOC** [6908-04]
J. Guenter, D. Mathes, B. Hawkins, J. Tatum, Finisar Advanced Optical Components Division (USA)

SESSION 2 HIGH-POWER VCSELS AND HIGH-SPEED VCSELS

- 6908 07 **Monolithic 2D high-power arrays of long-wavelength VCSELS** [6908-06]
W. Hofmann, M. Görblich, TU München (Germany); M. Ortsiefer, VERTILAS GmbH (Germany); G. Böhm, M.-C. Amann, TU München (Germany)
- 6908 08 **High-power high-efficiency 2D VCSEL arrays (Invited Paper)** [6908-07]
J.-F. Seurin, C. L. Ghosh, V. Khalfin, A. Miglo, G. Xu, J. D. Wynn, P. Pradhan, L. A. D'Asaro, Princeton Optronics (USA)
- 6908 09 **Development of high-speed VCSELS: 10 Gb/s serial links and beyond (Invited Paper)** [6908-22]
D. Collins, N. Li, Emcore Fiber Optics, Emcore Corp. (USA); D. Kuchta, F. Doany, C. Schow, IBM Thomas J. Watson Research Ctr. (USA); C. J. Helms, L. Yang, Emcore Fiber Optics, Emcore Corp. (USA)

SESSION 3 MICROSTRUCTURED VCSELS

- 6908 0A **Polarization-stable monolithic VCSELS (Invited Paper)** [6908-08]
R. Michalzik, J. M. Ostermann, Ulm Univ. (Germany); P. Debernardi, IEIT-CNR, Politecnico di Torino (Italy)
- 6908 0B **Endlessly single-mode photonic-crystal vertical-cavity surface-emitting lasers** [6908-09]
A. M. Kasten, M. P. Tan, Univ. of Illinois at Urbana-Champaign (USA); P. O. Leisher, nLight Photonics Corp. (USA); K. D. Choquette, Univ. of Illinois at Urbana-Champaign (USA)

- 6908 0C **Photonic crystals for long-wavelength single-mode VCSELs (Invited Paper)** [6908-10]
F. Romstad, S. Bischoff, M. Juhl, S. Jacobsen, D. Birkedal, Alight Technologies ApS
(Denmark)

SESSION 4 LONGER WAVELENGTH VCSEL CHARACTERISTICS

- 6908 0D **Singlemode 1.1 μm InGaAs quantum well microstructured photonic crystal VCSEL** [6908-11]
R. Stevens, P. Gilet, A. Larrue, L. Grenouillet, N. Olivier, P. Grosse, K. Gilbert, R. Teysseyre,
A. Chelnokov, CEA-LETI MINATEC, Lab. de Photonique sur Silicium (France)
- 6908 0E **Characteristics of GaInNAsSb/GaAs VCSELs operating near 1.55 μm** [6908-12]
J. A. Gupta, National Research Council of Canada (Canada); S. Calvez, N. Laurand,
J. Weda, D. Burns, Univ. of Strathclyde (United Kingdom); D. Poitras, G. C. Aers, National
Research Council of Canada (Canada); M. D. Dawson, Univ. of Strathclyde (United
Kingdom)
- 6908 0F **Spectral behavior of long wavelength VCSELs** [6908-13]
A. Bacou, A. Rissons, J.-C. Mollier, Univ. de Toulouse (France)

SESSION 5 VCSEL APPLICATIONS

- 6908 0G **Red vertical cavity surface emitting lasers (VCSELs) for consumer applications** [6908-14]
G. Duggan, D. A. Barrow, T. Calvert, M. Maute, V. Hung, B. McGarvey, J. D. Lambkin,
T. Wipiejewski, FireComms, Ltd. (Ireland)
- 6908 0H **VCSEL array-based light exposure system for laser printing (Invited Paper)** [6908-15]
N. Mukoyama, H. Otoma, J. Sakurai, N. Ueki, H. Nakayama, Fuji Xerox Co., Ltd. (Japan)
- 6908 0I **VCSEL-based miniature laser-Doppler interferometer** [6908-16]
A. Pruijboom, M. Schemmann, J. Hellmig, J. Schutte, Philips Laser Sensor (Netherlands);
H. Moench, Philips Research Europe (Germany); J. Pankert, Philips Lighting (Netherlands)
- 6908 0J **Modeling and characterization of VCSEL-based avionics full-duplex ethernet (AFDX)
gigabit links** [6908-17]
K. S. Ly, Airbus France SAS (France) and ISAE/MOSE Group (France); A. Rissons, ISAE/MOSE
Group (France); E. Gambardella, Airbus France SAS (France); D. Bajon, J.-C. Mollier,
ISAE/MOSE Group (France)

SESSION 6 VCSEL CHARACTERISTICS

- 6908 0L **Abnormal PL spectrum in InGaN MQW surface emitting cavity** [6908-19]
J. T. Chu, National Chiao Tung Univ. (Taiwan); Y.-J. Cheng, Academia Sinica (Taiwan);
H. C. Kuo, T. C. Lu, S. C. Wang, National Chiao Tung Univ. (Taiwan)
- 6908 0M **High frequency resonance-free loss modulation in a duo-cavity VCSEL** [6908-20]
J. van Eijsden, M. Yakimov, V. Tokranov, M. Varanasi, O. Romyantsev, Univ. at Albany (USA);
E. M. Mohammed, I. A. Young, Intel Corp. (USA); S. R. Oktyabrsky, Univ. at Albany (USA)

6908 0N

GaInNAsSb/GaAs vertical cavity surface-emitting lasers (VCSELs): current challenges and techniques to realize multiple-wavelength laser arrays at 1.55 μm [6908-21]

M. Gobet, H. P. Bae, T. Sarmiento, J. S. Harris, Ctr. for Integrated Systems (USA)

Author Index

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Session Chairs

- 1 Commercial VCSELS
Chun Lei, Intel Corporation (USA)
- 2 High-Power VCSELS and High-Speed VCSELS
Kent D. Choquette, University of Illinois at Urbana-Champaign (USA)
- 3 Microstructured VCSELS
Luke A. Graham, JDS Uniphase Corporation (USA)
- 4 Longer Wavelength VCSEL Characteristics
James K. Guenter, Finisar Corporation (USA)

- 5 VCSEL Applications
Martin Grabherr, ULM Photonics GmbH (Germany)
- 6 VCSEL Characteristics
Joachim J. Krueger, Novalux, Inc. (USA)

Introduction

2007 marked the 30th year after the first potentially realizable VCSEL was proposed, and just over a decade after the first commercial VCSEL products became available. Prior to 2007, the VCSEL commercial history had been overwhelmingly a story of data communications applications, almost all at 850 nm. Some time during 2007, however, other applications, particularly computer mice, began to use equal or greater numbers of VCSELs, and the long-predicted proliferation was officially afoot. In this, the 12th annual SPIE Photonics West conference on VCSELs, we find a wide range of current and potential VCSEL applications.

The VCSELs discussed in the presentations and in the papers in this volume cover half a dozen different wavelengths from the visible to 1.55 μm . Despite the VCSEL reputation for low maximum output power, arrays with cw power as high as 230 W in the infrared are described, as well as near-watt-level power in the blue and green through frequency doubling. In addition, results are presented for everything from single VCSEL elements to arrays of tens of thousands, and for speeds ranging from cw to 25 Gbps. The historical record of excellent VCSEL reliability was extended in the results of reliability testing of many of the variants.

In some ways the entire history of VCSELs is recapitulated in these papers, with structures both optically and electrically pumped, gain guides produced by oxidation but also by implantation, and novel structures such as coupled cavities and photonic crystals. Multiple solutions to typical problems are presented, for example four different, all successful, approaches to controlling polarization of the emission. Amazingly, all of these approaches have found or promise to find real application.

Overall, the papers in the 2008 VCSEL XII conference represent the current status of VCSEL development both in the research laboratory and in the commercial world, where VCSELs appear in tens of millions of systems each year—and growing.

**James Guenter
Chun Lei**

